

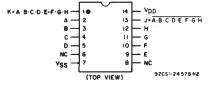
Data sheet acquired from Harris Semiconductor SCHS053C – Revised September 2003

CMOS 8-Input NAND/AND Gate

High-Voltage Types (20-Volt Rating)

■ CD4068B NAND/AND gate provides the system designer with direct implementation of the positive-logic 8-input NAND and AND functions and supplements the existing family of CMOS gates.

The CD4068B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).



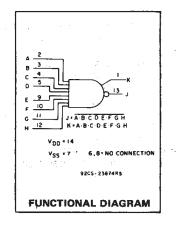
NE - NO CONNECTION

TERMINAL ASSIGNMENT

CD4068B Types

Features:

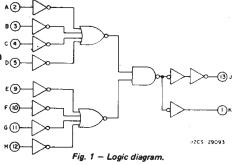
- Medium-Speed Operation: tpHL, tpLH = 75 ns (typ.) at VDD = 10 V
- Buffered inputs and outputs
- 5-V, 10-V, and 15-V parametric ratings
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range): 1 V at V_{DD} = 5 V
 2 V at V_{DD} = 10 V
 2.5 V at V_{DD} = 15 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	Min.	Max.	Unit
Supply Voltage Range			
(For T _A = Full Package		١	
Temperature Range)	3 -	18	V



STATIC ELECTRICAL CHARACTERISTICS

CHARACTER	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
ISTIC	Vo	O VIN VDD		+25			UNITS				
1. 1	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	1	0,5	5	0.25	0.25	7.5	7.5	-	0.01	0.25	
Current,		0,10	10	0.5	0.5	15	15	-	0.01	0.5	μА
IDD Max.	_	0,15	15	1	1	30	30	-	0.01	1	μ-
	_	0,20	20	5	5	150	150	-	0.02	5	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2,4	3 4	6.8		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1		mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Current, IOH Min.	9.5	0,10	10:	-1.6	-1.5	-1.1	-0.9	−1.3	−2.6		
TOH WITH	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:		0,5	5		0	.05		1	0	0.05	v
Low-Level, VOL Max.		0,10	10		0	.05		-	0	0.05	
AOF May.		0,15	15		0	.05		_	0	0.05	
Output Voltage:	_	0,5	5		4	95		4.95	5	-	
High-Level	-	0,10	10		9	95		9.95	10		
VOH Min.	-	0,15	15		14	.95		14.95	15	-	
Input Low	0.5,4.5	1	5		1	.5			_	1.5	
Voltage,	1,9	_	10			3		_	_	3	
V _{IL} Max. Input High Voltage,	1.5,13.5	_	15			4		_	Γ –	4	v
	0.5,4.5	-	5		3	3.5		3.5	_		V
	1,9	-	10			7		7			
VIH Min.	1.5,13.5	1	15		1	1		11		_	
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ

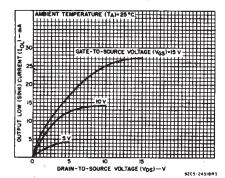


Fig. 2 — Typical output low (sink) current characteristics.

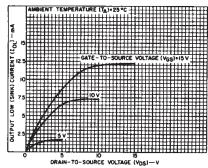


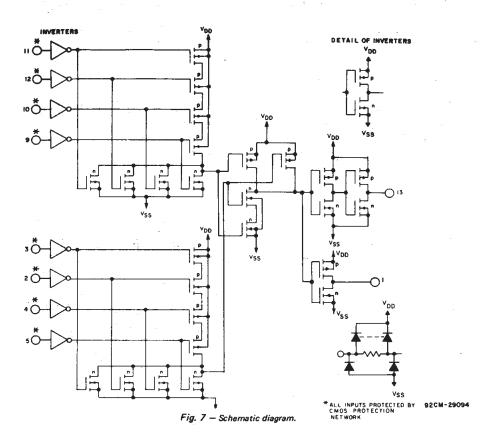
Fig. 3 — Minimum output low (sink) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS, Absolute-Maximum Values:

At $T_A = 25^{\circ}C$; Input t_r , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200k\Omega$

CHARACTERISTIC	TEST CONDI	LIA			
CHARACTERISTIC		V _{DD} VOLTS	TYP.	MAX.	UNITS
Propagation Delay Time,		5	150	300	
[†] PHL, [†] PLH		10	75	150	ns
		15	55	110	
		5	100	200	
Transition Time,		10	50	100	ns
ተተ ቤ ጥር ዘ		15	40	80	
Input Capacitance, C _{IN}	Any Input	-	5	7.5	pF



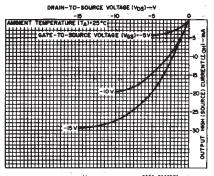


Fig. 4 — Typical output high (source) current characteristics.

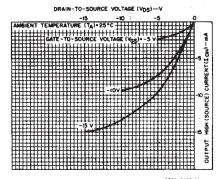


Fig. 5 — Minimum output high (source)

current characteristics.

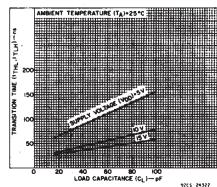


Fig. 6 — Typical transition time as a function of load capacitance.

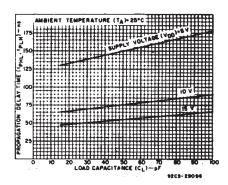


Fig. 8 — Typical propagation delay time as a function of load capacitance.

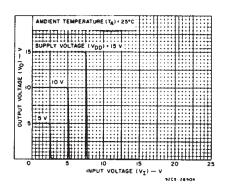


Fig. 9 — Typical voltage transfer characteristics (NAND output).

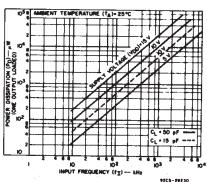


Fig. 10 - Typical dynamic power dissipation as a function of frequency.

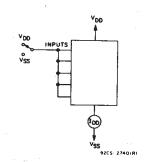


Fig. 11 - Quiescent-device-current test circuit.

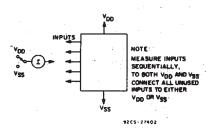


Fig. 12 - Input current test circuit.

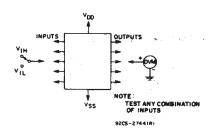


Fig. 13 - Input-voltage test circuit.

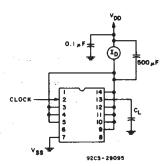
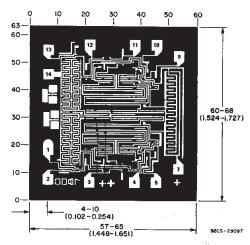


Fig. 14 – Dynamic power dissipation test circuit.



Dimensions and pad layout for CD4068BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3}) inch).







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
CD4068BE	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4068BEE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4068BF	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD4068BF3A	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD4068BM	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BM96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BM96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BMT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BMTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BNSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BNSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BPWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4068BPWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

6-Dec-2006

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14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AB.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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